TGA2527-SM Ku-Band Power Amplifier

#### Applications

- Point-to-Point Radio
- Ku-Band VSAT



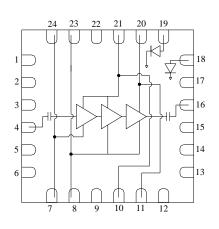


QFN 5x5mm 24L

#### **Functional Block Diagram**



- Frequency Range: 12.5 15.5 GHz
- TOI: 41 dBm
- Power: 31.5 dBm Psat, 30 dBm P1dB
- Gain: 25 dB
- Return Loss: 10 dB
- NF: 7.5 dB
- Integrated Power Detector
- Bias: Vd = 6 V, Id = 650 mA, Vg = -0.55 V Typical
- Package Dimensions: 5.0 x 5.0 x 0.85 mm



#### General Description

The TriQuint TGA2527-SM is a Ku-Band Packaged Power Amplifier. The TGA2527-SM operates from 12.5 to 15.5 GHz and is designed using TriQuint's power pHEMT production process.

The TGA2527-SM typically provides 41dBm of TOI at 20dBm Pout/Tone, 30 dBm of output power at 1dB gain compression, and the small signal gain is 25 dB.

The TGA2527-SM is available in a low-cost, surface mount 24 lead 5x5 QFN package and is ideally suited for Point-to-Point Radio, and Ku-Band VSAT Ground Terminal.

Lead-free and RoHS compliant.

Evaluation Boards are available upon request.

#### Pin Configuration

Pin #	Symbol
1, 2, 3, 5, 6, 9, 12, 13, 14, 15, 17	N/C
4	RF IN
7, 8, 23, 24	Vg
16	RF OUT
10, 11, 20, 21	Vd
18	Vref
19	Vdet
22	GND

#### **Ordering Information**

Part No.	ECCN	Description		
TGA2527-SM	3A001.b.2.c	Ku-band Power Amplifier		
Standard T/R size = 500 pieces on a 7" reel.				

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#### **Specifications**

#### Absolute Maximum Ratings

Parameter	Rating
Drain Voltage,Vd	+8 V
Gate Voltage,Vg	-3 to 0 V
Drain Current, Id	1.12 A
Gate Current, Ig	-5.5 to 88 mA
Power Dissipation, Pdiss	9 W
RF Input Power, CW, $50\Omega$ , T = $25^{\circ}$ C	24 dBm
Channel Temperature, Tch	200 °C
Mounting Temperature (30 Seconds)	260 °C
Storage Temperature	-40 to 150 °C

Operation of this device outside the parameter ranges given above may cause permanent damage. These are stress ratings only, and functional operation of the device at these conditions is not implied.

#### **Recommended Operating Conditions**

Parameter	Min	Typical	Max	Units
Vd		6		V
Id		650		mA
Id_drive (Under RF Drive)		850		mA
Vg		-0.55		V

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

## **Electrical Specifications**

Test conditions unless otherwise noted: 25°C, Vd = 6 V, Id = 650 mA, Vg = -0.55 V Typical.

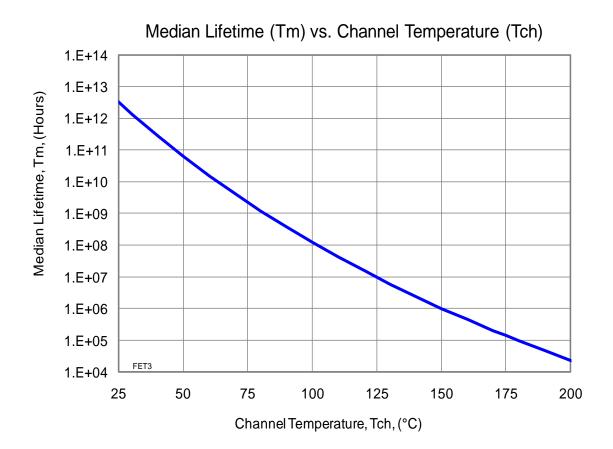
Parameter	Min	Typical	Max	Units
Operational Frequency Range	12.5		15.5	GHz
Gain		25		dB
Input Return Loss		-10		dB
Output Return Loss		-10		dB
Output Power @ Saturation		31.5		dBm
Output Power @ 1 dB Gain Compression		30		dBm
Output TOI @ Pout/Tone = 20 dBm		41		dBm
Noise Figure		7.5		dB
Gain Temperature Coefficient		-0.033		dB/°C
Power Temperature Coefficient		-0.005		dBm/°C



#### **Specifications (cont.)**

## **Thermal and Reliability Information**

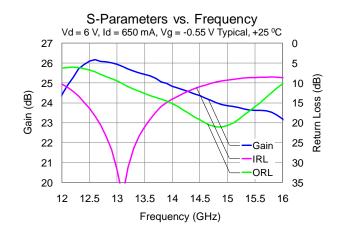
Parameter	Condition	Rating
Thermal Resistance, $\theta_{JC}$ , measured to back of package	Tbase = $85 \degree C$	$\theta_{\rm JC} = 11.5 \ {\rm ^{\circ}C/W}$
Channel Temperature (Tch), and Median Lifetime (Tm)	Tbase = $85 \degree C$ , Vd = 6 V, Id = $650 \ mA$ ,	$Tch = 130 \ ^{\circ}C$
Channel Temperature (TCh), and Median Effettine (Thi)	Pdiss = 3.9 W	Tm = 5.9 E+6 Hours
Channel Temperature (Tch), and Median Lifetime (Tm)	Tbase = $85 \degree C$ , Vd = $6 V$ , Id = $850 mA$ ,	Tch = 125 °C
Under RF Drive	Pout = $32 \text{ dBm}$ , Pdiss = $3.5 \text{ W}$	Tm = 9.5 E+6 Hours

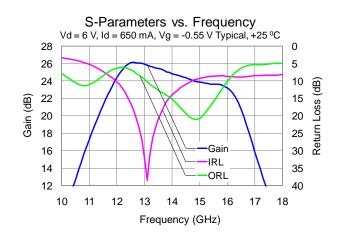


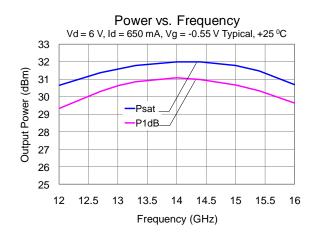
# TGA2527-SM **Ku-Band Power Amplifier**

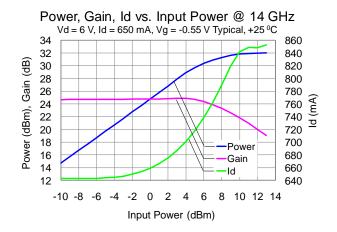


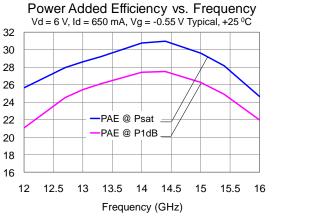
#### **Typical Performance**











Power Detector vs. Pout vs. Frequency Vd = 6 V, Id = 650 mA, Vg = -0.55 V Typical, +25 °C 10 1 Vdiff (V) 12.7GHz 0.1 13.3GHz 14.4GHz 15.4GHz 0.01 -5 0 5 10 15 20 25 30 Output Power (dBm)

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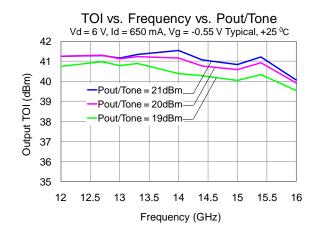
PAE (%)

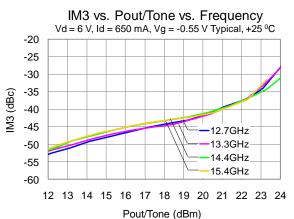
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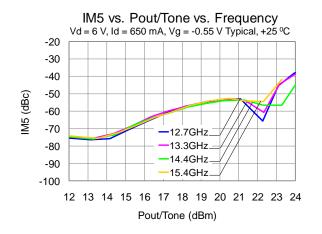
35



#### **Typical Performance (cont.)**







Gain vs. Frequency vs. Bias

Vd = 5 - 6 V, Id = 600 - 700 mA, +25 °C

6V 700mA

6V 650mA

6V 600mA

5V 650mA

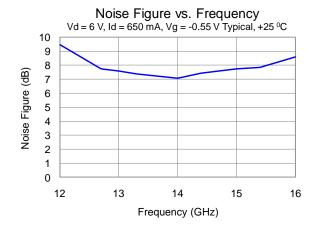
14.5

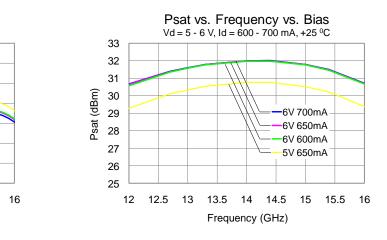
15

15.5

14

Frequency (GHz)





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13.5

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23

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20

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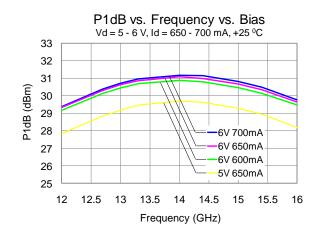
12.5

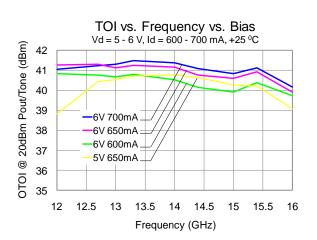
Gain dB 24

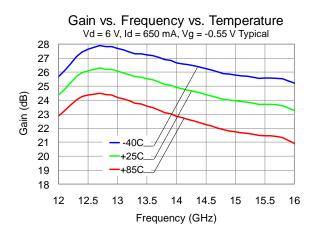
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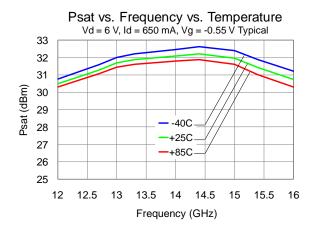


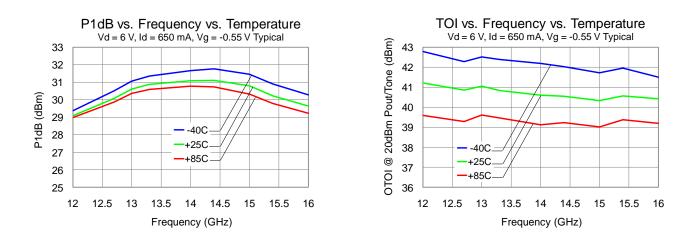
#### **Typical Performance (cont.)**











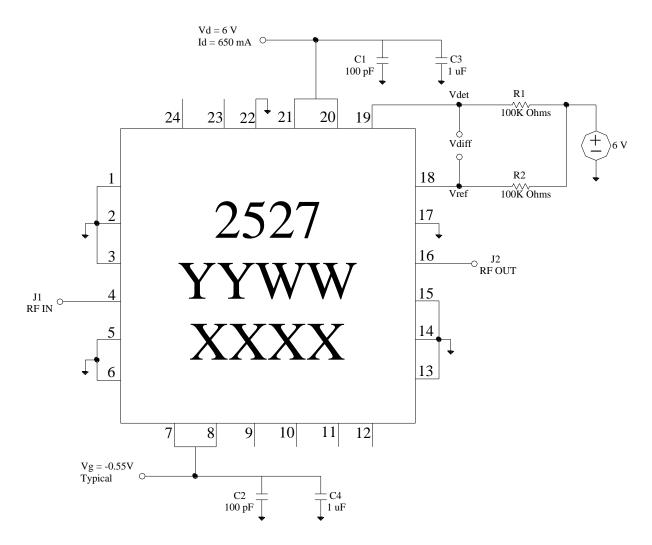
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# TGA2527-SM

Ku-Band Power Amplifier



#### **Application Circuit**



Vg and Vd can be biased from either side, and the non-biased side can be left open. (Vg are either pins 7 and 8 or pins 23 and 24, Vd are either pins 10 and 11 or pins 20 and 21)

Bias-up Procedure	Bias-down Procedure
Vg set to -1.5 V	Turn off RF supply
Vd set to +6 V	Reduce Vg to -1.5V. Ensure Id ~ 0 mA
Adjust Vg more positive until quiescent Id is 650mA. This will be ~ Vg = $-0.55$ V	Turn Vd to 0 V
Apply RF signal to RF Input	Turn Vg to 0 V

The TGA2527-SM will be marked with the "2527" designator and a lot code marked below the part designator. The "YY" represents the last two digits of the year the part was manufactured, the "WW" is the work week, and the "XXXX" is an autogenerated number.

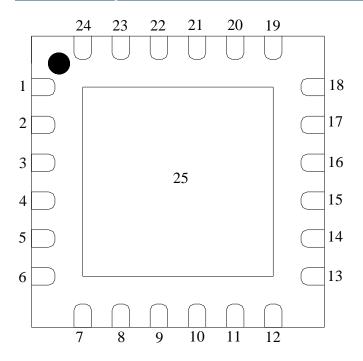
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# TGA2527-SM

Ku-Band Power Amplifier



## **Pin Description**



Pin	Symbol	Description
1, 2, 3, 5, 6, 13, 14, 15, 17	N/C	No internal connection; must be grounded on PCB
4	RF IN	Input, matched to 50 ohms
7, 8, 23, 24	Vg	Gate voltage. ESD protection included; Bias network is required; can be biased from either side (pins 7 and 8 or pins 23 and 24), and non-biased side can be left opened; see Application Circuit on page 7 as an example.
9, 12	N/C	No internal connection. Can be grounded on PCB or left open
10, 11, 20, 21	Vd	Drain voltage. Bias network is required; can be biased from either side (pins 10 and 11 or pins 20 and 21), and non-biased side can be left opened; see Application Circuit on page 7 as an example.
16	RF OUT	Output, matched to 50 ohms
18	Vref	Reference diode output voltage.
19	Vdet	Detector diode output voltage. Varies with RF output power.
22	GND	Internal grounding; can be grounded on PCB or left open
25	GND	Backside Paddle. Multiple vias should be employed to minimize inductance and thermal resistance; see Mounting Configuration on page 11 for suggested footprint.



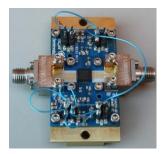
#### **Applications Information**

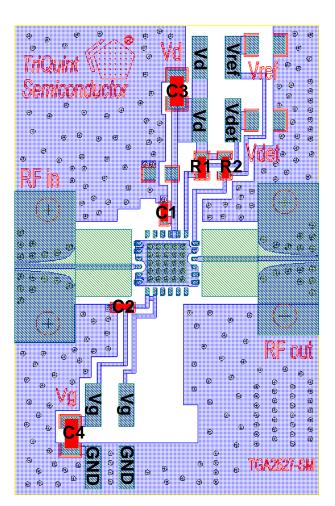
#### PC Board Layout

Top RF layer is 0.008" thick Rogers RO4003,  $\epsilon_r = 3.38$ . Metal layers are 1-oz copper. Microstrip 50  $\Omega$  line detail: width = 0.0175".

The pad pattern shown has been developed and tested for optimized assembly at TriQuint Semiconductor. The PCB land pattern has been developed to accommodate lead and package tolerances. Since surface mount processes vary from company to company, careful process development is recommended.

For further technical information, refer to the <u>TGA2527-SM</u> Product Information page.





#### **Bill of Material**

Ref Des	Value	Description	Manufacturer	Part Number
C1, C2	100 pF	Cap, 0402, 50 V, 5%, COG	various	
C3, C4	1 uF	Cap, 0603, 25 V, 10%, X5R	various	
R1, R2	100K Ohms	Res, 0603, 1/16W, 5%, SMD	various	

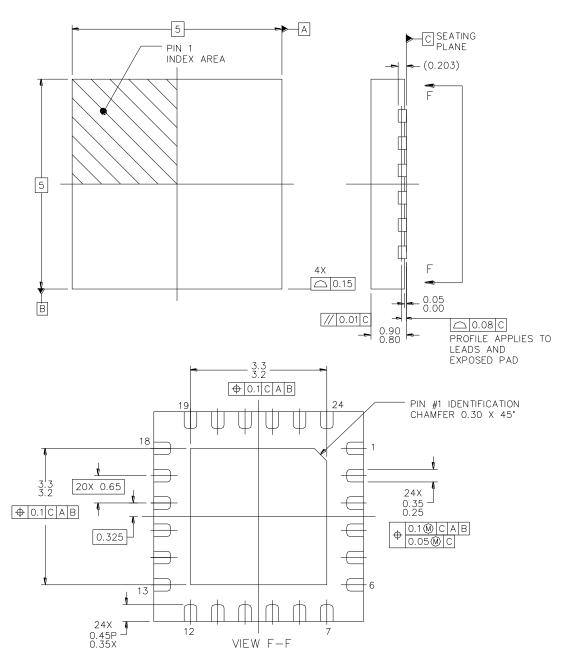
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#### **Mechanical Information**

#### **Package Information and Dimensions**

All dimensions are in millimeters.



This package is lead-free/RoHS-compliant with a copper alloy base (CDA194), and the plating material on the leads is 100% matte Sn. It is compatible with both lead-free (maximum 260 °C reflow temperature) and tin-lead (maximum 245 °C reflow temperature) soldering processes.

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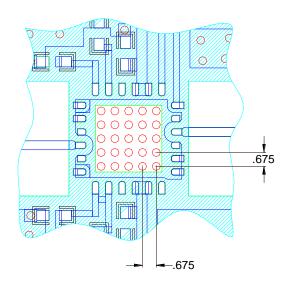
#### **Mechanical Information (cont.)**

#### **Mounting Configuration**

All dimensions are in millimeters (inches).

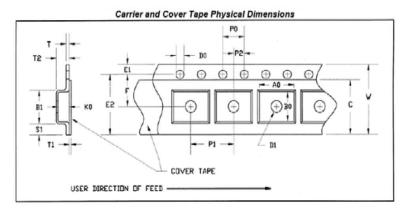
#### Notes:

- 1. A heatsink underneath the area of the PCB for the mounted device is recommended for proper thermal operation.
- 2. Ground / thermal vias are critical for the proper performance of this device. Vias have a final plated thru diameter of .40 mm (.016").



#### Tape and Reel Information

Tape and reel specifications for this part are also available on the TriQuint website in the "Application Notes" section. Standard T/R size = 500 pieces on a 7 x 0.5" reel.



#### **CARRIER AND COVER TAPE DIMENSIONS**

Part	Feature	Symbol	Size (in)	Size (mm)
Cavity	Length	A0	0.207	5.25
	Width	B0	0.207	5.25
	Depth	K0	0.043	1.10
	Pitch	P1	0.315	8.00
Distance Between Centerline	Cavity to Perforation Length Direction	P2	0.079	2.00
	Cavity to Perforation Width Direction	F	0.217	5.50
Cover Tape	Width	С	0.374	9.5
Carrier Tape	Width	W	0.472	12.0

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#### **Product Compliance Information**

#### **ESD** Information



ESD Rating:TBDValue:Passes  $\geq$  TBD minTest:Human Body ModeStandard:JEDEC Standard JI

Human Body Model (HBM) JEDEC Standard JESD22-A114

#### **MSL** Rating

Level MSL1 at +260 °C convection reflow The part is rated Moisture Sensitivity Level MSL1 at 260°C per JEDEC standard IPC/JEDEC J-STD-020.

## ECCN

US Department of Commerce 3A001.b.2.c

#### **Recommended Soldering Temperature Profile**

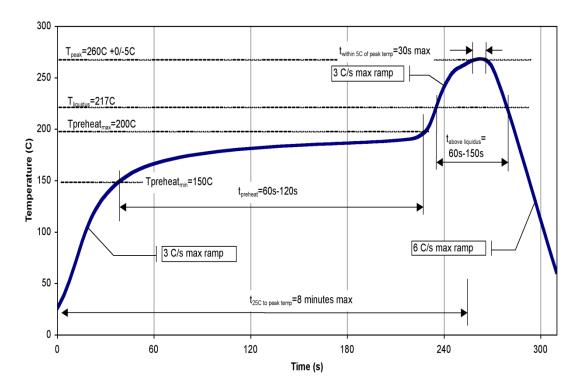


Compatible with the latest version of J-STD-020, Lead free solder,  $260^{\circ}$ C

This part is compliant with EU 2002/95/EC RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment).

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A ( $C_{15}H_{12}Br_40_2$ ) Free
- PFOS Free
- SVHC Free





#### **Contact Information**

For the latest specifications, additional product information, worldwide sales and distribution locations, and information about TriQuint:

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